BF959

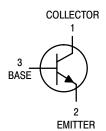
VHF Transistor

NPN Silicon



ON Semiconductor™

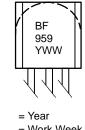
http://onsemi.com





CASE 29 STYLE 21

MARKING DIAGRAM



Υ = Work Week

ORDERING INFORMATION

Device	Package	Shipping
BF959	TO-92	5000 Units/Box
BF959ZL1	TO-92	2000/Ammo Pack
BF959RL1	TO-92	2000 Units/Box

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	20	Vdc
Collector-Base Voltage	VCBO	30	Vdc
Emitter-Base Voltage	VEBO	3.0	Vdc
Collector Current – Continuous	IC	100	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

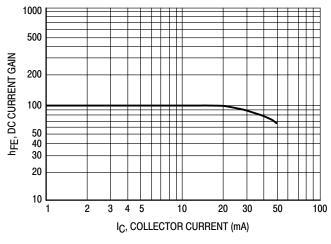
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ heta$ JC	83.3	°C/W

BF959

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

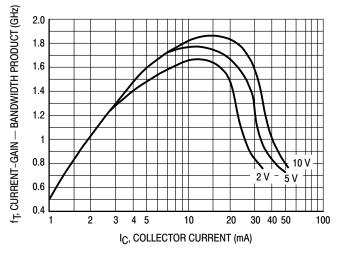
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•		
Collector–Emitter Breakdown Voltage (I _C = 1.0 mAdc, I _B = 0)	V(BR)CEO	20	_	_	Vdc
Collector–Base Breakdown Voltage (I _C = 10 μAdc, I _E = 0)	V(BR)CBO	30	_	_	Vdc
Emitter–Base Breakdown Voltage (I _E = 10 μAdc, I _C = 0)	V(BR)EBO	3.0	_	_	Vdc
Collector Cutoff Current (V _{CB} = 20 Vdc, I _E = 0)	ICBO	_	_	100	nAdc
ON CHARACTERISTICS					
DC Current Gain ($I_C = 5.0 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$) ($I_C = 20 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$)	hFE	35 40		- -	_
Collector-Emitter Saturation Voltage (I _C = 30 mAdc, I _B = 2.0 mAdc)	V _{CE(sat)}	_	_	1.0	Vdc
Base–Emitter Saturation Voltage (I _C = 30 mAdc, I _B = 2.0 mAdc)	V _{BE(sat)}	_	_	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain – Bandwidth Product ($I_C = 20 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, $f = 100 \text{ MHz}$) ($I_C = 30 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, $f = 100 \text{ MHz}$)	fT	700 600	- -	- -	MHz
Common Emitter Feedback Capacitance (V _{CB} = 10 Vdc, P _f = 0, f = 10 MHz)	C _{re}	-	0.65	-	pF
Noise Figure (I _C = 4.0 mA, V_{CE} = 10 V, R_{S} = 50 Ω , f = 200 MHz)	N _f	_	3.0	_	dB



200
200
100
20
40
30
20
10 1 2 3 4 5 10 20 30 50
IC, COLLECTOR CURRENT (mA)

Figure 1. hFE at 10 V

Figure 2. $V_{CE(sat)}$ at $I_{C}/I_{B} = 10$



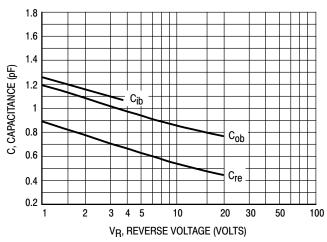
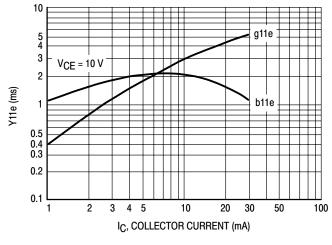


Figure 3. Current-Gain - Bandwidth Product

Figure 4. Capacitances



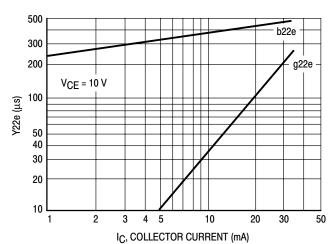


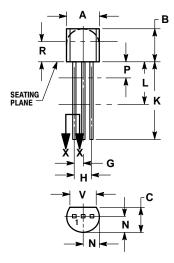
Figure 5. Input Impedance at 30 MHz

Figure 6. Output Impedance at 30 MHz

BF959

PACKAGE DIMENSIONS

TO-92 TO-226AA CASE 29-11 **ISSUE AL**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		

STYLE 21: PIN 1. COLLECTOR STYLE 14:

PIN 1. EMITTER COLLECTOR EMITTER 2. 2.

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